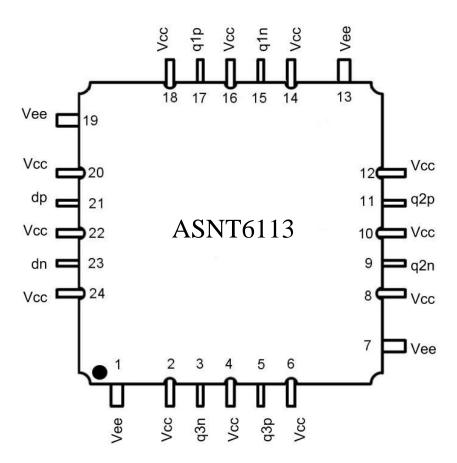


Ultra High-Speed Mixed Signal ASICs

Offices: 310-530-9400 / Fax: 310-530-9402 www.adsantec.com

ASNT6113-KMC DC-25*GHz* 1-to-3 Analog Signal Splitter

- DC to 25*GHz* broadband linear signal splitter
- One differential CML-type input port and three phase-matched differential CML-type output ports
- Differential input linearity range up to 1000mV p-p
- Differential gain of approximately 0dB
- Low jitter and limited temperature variation over industrial temperature range
- Single +3.3V or -3.3V power supply
- Power consumption: 1.0W
- Fabricated in SiGe for high performance, yield, and reliability
- Custom CQFP 24-pin package





DESCRIPTION

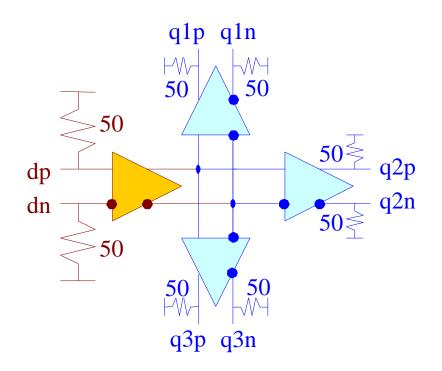


Fig. 1. Functional Block Diagram

The temperature stable ASNT6113-KMC 1-to-3 analog signal splitter is intended for use in high-speed interleaved ADCs or similar systems. The IC shown in Fig. 1 can receive a broad-band analog signal at its differential input dp/dn and effectively distribute it to three separate phase matched differential outputs q1p/q1n, q2p/q2n, q3p/q3n with a nominal gain of 0*dB*.

The part's I/O's support the CML logic interface with on chip 50*Ohm* termination to vCC and may be used differentially, AC/DC coupled, single-ended, or in any combination (also see POWER SUPPLY CONFIGURATION). In the DC-coupling mode, the input signal's common mode voltage should comply with the specifications shown in ELECTRICAL CHARACTERISTICS. In the AC-coupling mode, the input termination provides the required common mode voltage automatically. The differential DC signaling mode is recommended for optimal performance. In particular, the specified output common mode voltage level is guaranteed only in case of external single-ended 50*Ohm* DC termination to vCC.

POWER SUPPLY CONFIGURATION

The part can operate with either negative supply (vcc = 0.0V = ground and vee = -3.3V), or positive supply (vcc = +3.3V and vee = 0.0V = ground). In case of the positive supply, all I/Os need AC termination when connected to any devices with 50*Ohm* termination to ground. Different PCB layouts will be needed for each different power supply combination.

All the characteristics detailed below assume vcc = 0.0V and vee = -3.3V.



ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings shown in Table 1 may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied. All min and max voltage limits are referenced to ground.

Parameter	Min	Max	Units
Supply Voltage (vee)		-3.6	V
Power Consumption		1.1	W
RF Input Voltage Swing (SE)		1.4	V
Case Temperature		+90	°С
Storage Temperature	-40	+100	°С
Operational Humidity	10	98	%
Storage Humidity	10	98	%

Table 1	. Absolute	Maximum	Ratings
10010 1	. 1105011110	111000000000000000000000000000000000000	Innings

TERMINAL FUNCTION

TI	TERMINAL			DESCRIPTION	
Name	No.	Туре			
dp	21	CML	Differential high speed data inputs with internal SE 500hm		
dn	23	input	termination to VCC		
q1p	17	CML	Differential high speed data outputs with internal SE 500hm		
q1n	15	output	termination to vcc. Require external SE 50 <i>Ohm</i> termination to vcc		
q2p	11	CML			
q2n	9	output			
q3p	5	CML			
q3n	3	output			
Supply and Termination Voltages					
Name	Description		scription	Pin Number	
vcc	Positive power supply $(+3.3V \text{ or } 0)$		r supply $(+3.3V \text{ or } 0)$	2, 4, 6, 8, 10, 12, 14, 16, 18, 20, 22, 24	
vee	Negative power supply $(0V \text{ or } -3.3V)$		r supply (0 <i>V</i> or -3.3 <i>V</i>)	1, 7, 13, 19	



ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
General Parameters					
vee	-3.1	-3.3	-3.5	V	$\pm 6\%$
VCC		0.0		V	External ground
Ivee		300		mA	
Power consumption		1000		mW	
Junction temperature	-25	50	125	$^{\circ}C$	
	Inp	out Analo	g (dp/dn)		
Bandwidth	DC		25	GHz	-3 <i>dB</i>
Common mode level	vcc-0.6	vcc-0.5	vcc-0.4	mV	
Input Noise Density		1.5		<i>nV</i> /sqrt(<i>Hz</i>)	
S11		-10		dB	DC to 30GHz
Output Analog (q1p/q1n, q2p/q2n, q3p/q3n)					
Common mode level		vcc-0.55		V	With external 500hm
					DC termination
S22		-8		dB	DC to 30GHz
Small Signal Differential Gain		0		dB	at 10GHz
Output referred 1 <i>dB</i> Compression Point		2.7		dBm	Single-Ended, 20GHz
THD		0.2		%	

PACKAGE INFORMATION

The chip die is housed in a custom 24-pin CQFP package shown in Fig. 2. The package provides a center heat slug located on its back side to be used for heat dissipation. ADSANTEC recommends for this section to be soldered to the **vcc** plain, which is ground for a negative supply, or power for a positive supply.

The part's identification label is ASNT6113-KMC. The first 8 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 3 characters after the dash represent the package's manufacturer, type, and pin out count.

This device complies with the Restriction of Hazardous Substances (RoHS) per 2011/65/EU for all ten substances.



LDSLLTEG Ultra High-Speed Mixed Signal ASICs

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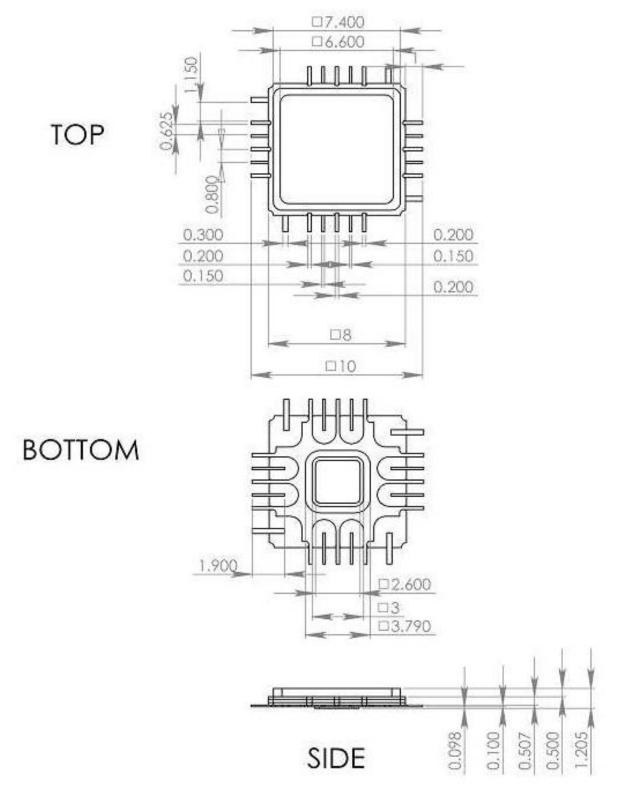


Fig. 2. CQFP 24-Pin Package Drawing (All Dimensions in mm)



REVISION HISTORY

Revision	Date	Changes	
1.3.2	05-2020	Updated Package Information	
1.2.2	07-2019	Updated Letterhead	
1.2.1	05-2015	Revised Package Information section	
		Updated format	
1.1.1	03-2013	Corrected description	
		Corrected absolute maximum ratings	
		Updated Electrical Specifications table	
		Added package mechanical drawing	
		Corrected format	
1.0	03-2012	First release	